

# Zeners BZX55C2V4 - BZX55C91

## Absolute Maximum Ratings \* T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
P <sub>D</sub>	Power Dissipation	500	mW
	@ TL ≤ 75°C, Lead Length = 3/8"		
	Derate above 75°C	4.0	mW/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-65 to +200	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of the diode may be impaired.



## Electrical Characteristics T<sub>A</sub>=25°C unless otherwise noted

Device	V <sub>Z</sub> (V) @	I <sub>Z</sub> (Note 1)	Z <sub>Z</sub> @ I <sub>Z</sub>	Test Current	I <sub>1</sub>	<sub>R</sub> (μΑ) @ V <sub>R</sub>		I <sub>ZM</sub> (mA)
Device	Min.	Max.	(Ω)	I <sub>Z</sub> (mA)	Ta = 25°C	Ta = 125°C	V <sub>R</sub> (V)	(Note 2)
BZX55C2V4	2.28	2.56	85	5	50	100	1	155
BZX55C2V7	2.50	2.9	85	5	10	50	1	135
BZX55C3V0	2.8	3.2	85	5	4	40	1	125
BZX55C3V3	3.1	3.5	85	5	2	40	1	115
BZX55C3V6	3.4	3.8	85	5	2	40	1	105
BZX55C3V9	3.7	4.1	85	5	2	40	1	95
BZX55C4V3	4.0	4.6	75	5	1	40	1	90
BZX55C4V7	4.4	5.0	60	5	0.5	10	1	85
BZX55C5V1	4.8	5.4	35	5	0.1	2	1	80
BZX55C5V6	5.2	6.0	25	5	0.1	2	1	70
BZX55CT6V2	5.8	6.6	10	5	0.1	2	2	64
BZX55CT6V8	6.4	7.2	8	5	0.1	2	3	58
BZX55CT7V5	7.0	7.9	7	5	0.1	2	5	53
BZX55CT8V2	7.7	8.7	7	5	0.1	2	6	47
BZX55CT9V1	8.5	9.6	10	5	0.1	2	7	43
BZX55CT10	9.5	10.6	15	5	0.1	2	7.5	40
BZX55CT11	10.4	11.6	20	5	0.1	2	8.5	36
BZX55CT12	11.4	12.7	20	5	0.1	2	9	32
BZX55CT13	12.4	14.1	26	5	0.1	2	10	29
BZX55CT15	13.8	15.6	30	5	0.1	2	11	27
BZX55CT16	15.3	17.1	40	5	0.1	2	12	24
BZX55CT18	16.8	19.1	50	5	0.1	2	14	21
BZX55CT20	18.8	21.1	55	5	0.1	2	15	20
BZX55C22	20.8	23.3	55	5	0.1	2	17	18
BZX55C24	22.8	25.6	80	5	0.1	2	18	16
BZX55C27	25.1	28.9	80	5	0.1	2	20	14
BZX55C30	28.0	32.0	80	5	0.1	2	22	13
BZX55C33	31.0	35.0	80	5	0.1	2	24	12
BZX55C36	34.0	38.0	80	5	0.1	2	27	11
BZX55C39	37.0	41.0	90	2.5	0.1	5	28	10

# $\textbf{Electrical Characteristics} \hspace{0.1cm} \text{(Continued)} \hspace{0.1cm} \textbf{T}_{A} = 25 \, ^{\circ} \textbf{C} \hspace{0.1cm} \text{unless otherwise noted}$

Device	V <sub>Z</sub> (V) @ I <sub>Z</sub> (Note 1)		Z <sub>Z</sub> @ I <sub>Z</sub>	Test Current	I <sub>R</sub> (μΑ) @ V <sub>R</sub>			I <sub>ZM</sub> (mA)
Device	Min.	Max.	(Ω)	I <sub>Z</sub> (mA)	Ta = 25°C	Ta = 125°C	V <sub>R</sub> (V)	(Note 2)
BZX55C43	40	46	90	5	0.1	5	32	9.2
BZX55C47	44	50	110	5	0.1	5	35	8.5
BZX55C51	48	54	125	5	0.1	10	38	7.8
BZX55C56	52	60	135	5	0.1	10	42	7.0
BZX55C62	58	66	150	5	0.1	10	47	6.4
BZX55C68	64	72	160	5	0.1	10	51	5.9
BZX55C75	70	80	170	5	0.1	10	56	5.3
BZX55C82	77	87	200	5	0.1	10	62	4.8
BZX55C91	85	96	250	1	0.1	10	69	4.3

V<sub>F</sub> Forward Voltage = 1.3V Max @ I<sub>F</sub> = 100mA

#### Notes:

- Notes:

  1. Zener Voltage (V<sub>Z</sub>)
  The zener voltage is measured with the device junction in the themal equilibrium at the lead temperature (T<sub>L</sub>) at 30°C ± 1°C and 3/8" lead length.

  2. Maximum Zener Current Ratings (I<sub>ZM</sub>)
  The maximum current handling capability on a worst case basis is limited by the actual zener voltage at the operation point and the power derating curve.

### **TRADEMARKS**

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ΑŒ	CEx™	FACT™	ImpliedDisconnect™	PACMAN™	SPM™
Αc	ctiveArray™	FACT Quiet Series™	ISOPLANAR™	POP™	Stealth™
В	ottomless™	FAST®	LittleFET™	Power247™	SuperSOT™-3
Co	oolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CI	ROSSVOLT™	FRFET™	MicroPak™	QFET®	SuperSOT™-8
D	OME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
E	coSPARK™	GTO™ .	MSX™	QT Optoelectronics™	TinyLogic <sup>®</sup>
$E^2$	<sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
Er	nSigna™	I <sup>2</sup> C <sup>TM</sup>	$OCX^{TM}$	RapidConfigure™	UHC™
A	cross the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
Th	ne Power Franch	nise™	OPTOLOGIC®	SILENT SWITCHER®	VCX™
Pı	rogrammable Ac	tive Droop™	OPTOPLANAR™	SMART START™	

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition		
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.		
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.		
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.		